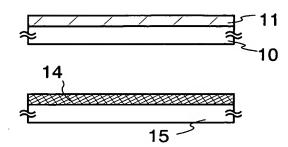
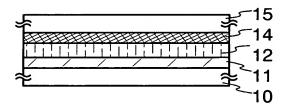


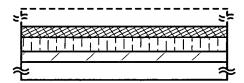
(A)



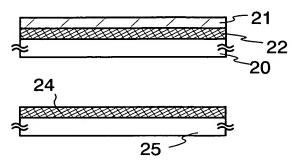
(B) A state of the second substrate 15 after the adhesion



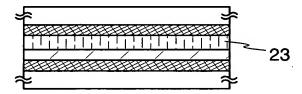
(C) Dissolution and removal processes of the second substrate 15



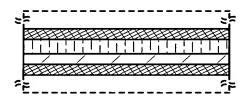
(A) After forming a layer to be peeled



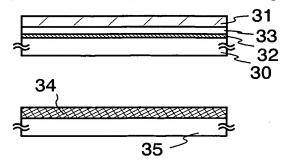
(B) A state of the second substrate 25 after the adhesion



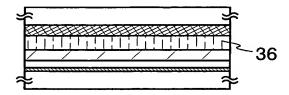
(C) Dissolution and removal processes of the second substrate 25



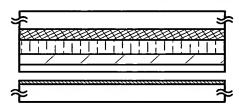
(A) After forming a layer including an element



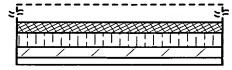
(B) A state of the second substrate 35 after the adhesion



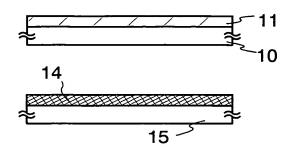
(C) A state of the first substrate 30 after peeling



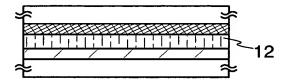
(D) Dissolution and removal processes of the second substrate 35



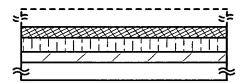
(A) After forming a layer to be peeled



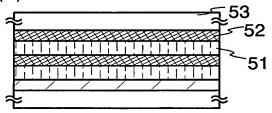
(B) A state of the second substrate 15 after the adhesion



(C) Dissolution and removal processes of the second substrate 15



(D) A state of a third substrate after the adhesion



Dissolution and removal processes of the third substrate 53

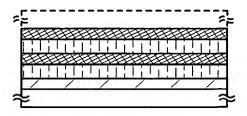
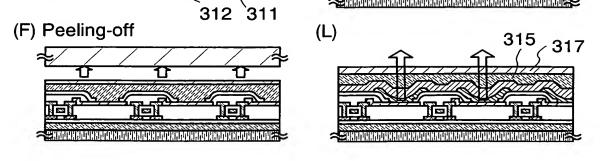
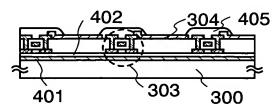


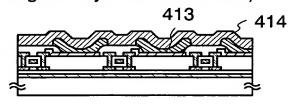
FIG. 5 (A) After forming a layer to be peeled 302 <u>304</u>∠ 305a (G) Peeling-off 303 301 300 (B) Coating of water soluble resin **∠306** (H) Removal of water soluble resin (C) Bonding with a double-stick tape 308 ,307 (I) Formation of an organic compound layer and a cathode 314 310 `309 (D) Peeling-off (J) Bonding a glass substrate 317315316 HIDOORISH TOO OKKADOORIKA OO OKKADOORIK GAARII KAADOORIKA OO OKKADOORII HAGAALEK OO OKKADO (K) Etching of a glass substrate (E) Bonding of a plastic substrate 315,317



(A) A formation of a layer to be peeled (TFT)

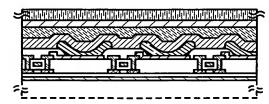


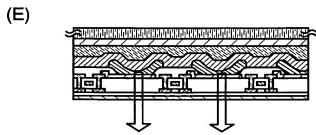
(B) A formation of a layer to be peeled (an organic layer and a cathode)



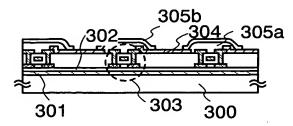
(C) Sealing 417 415 416

(D) Etching of a glass substrate

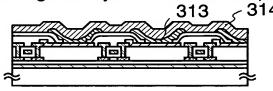




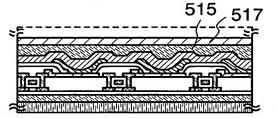
(A) A formation of a layer to be peeled (TFT)

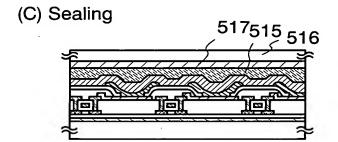


(B) A Formation of a layer to be peeled (an organic layer and a cathode)

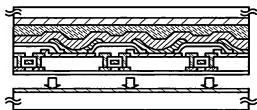


(F) Etching of a quartz substrate



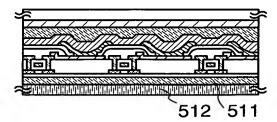


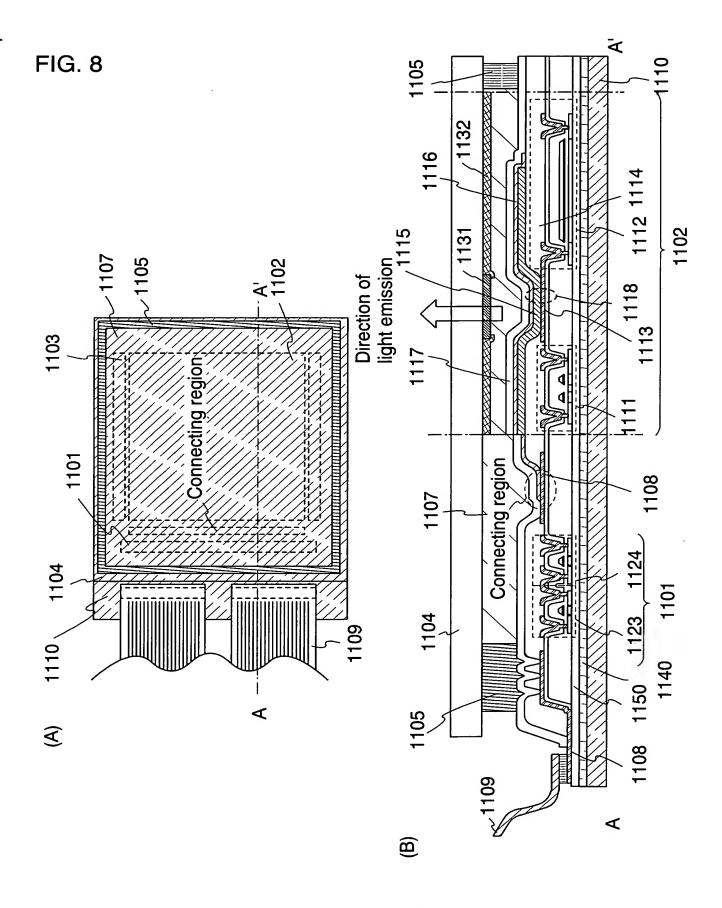
(D) Separating of a glass substrate



(G)

(E) Bonding of a plastic substrate





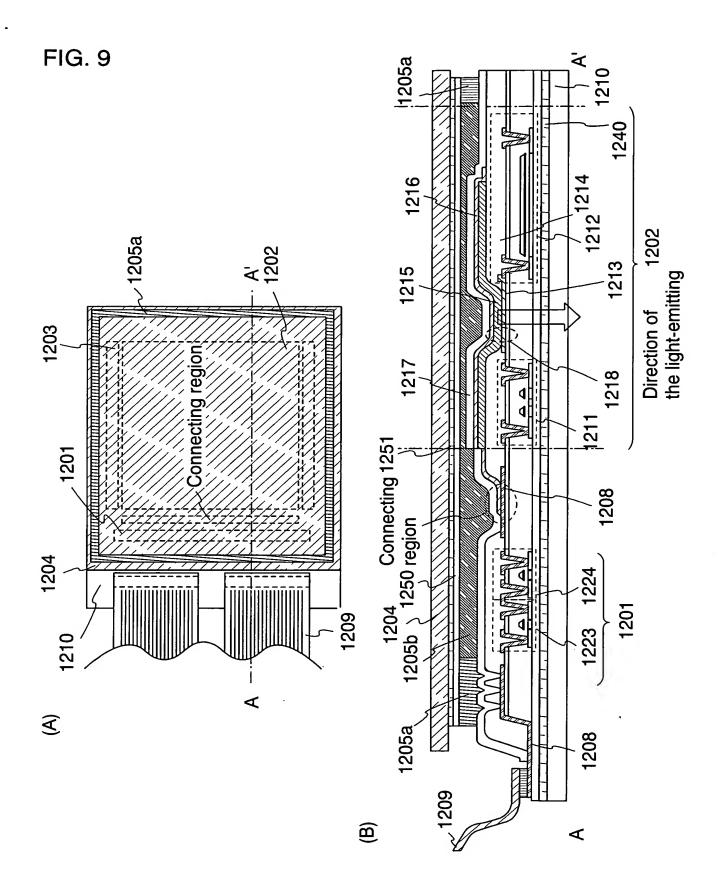
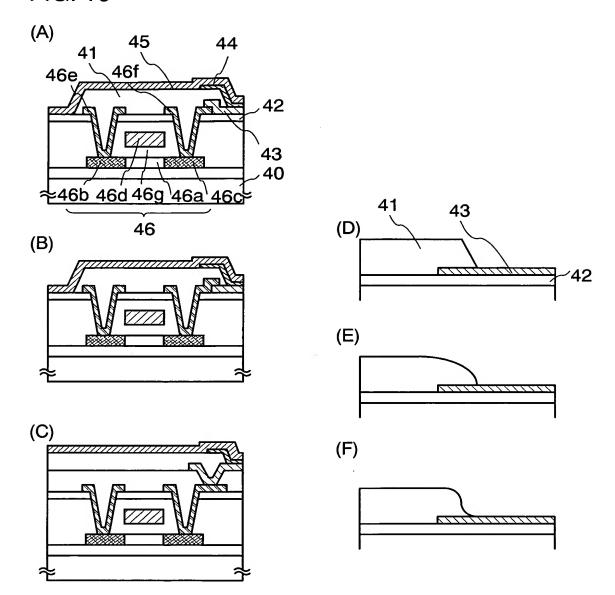
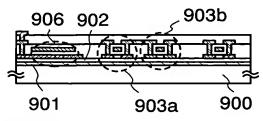


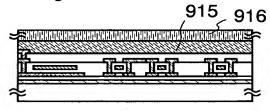
FIG. 10



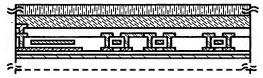
(A) A configuration of a layer to be peeled (CPU including CMOS circuit)



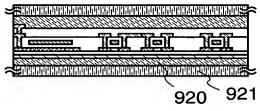
(B) Sealing



(C) Etching of a glass substrate



(D) Bonding



(E) Peeling-off



FIG. 12

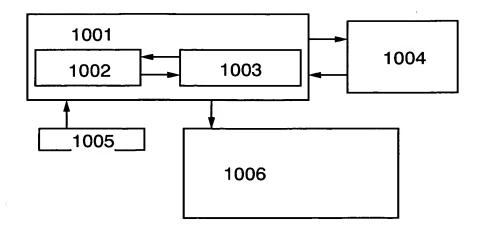


FIG. 13

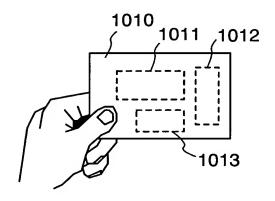
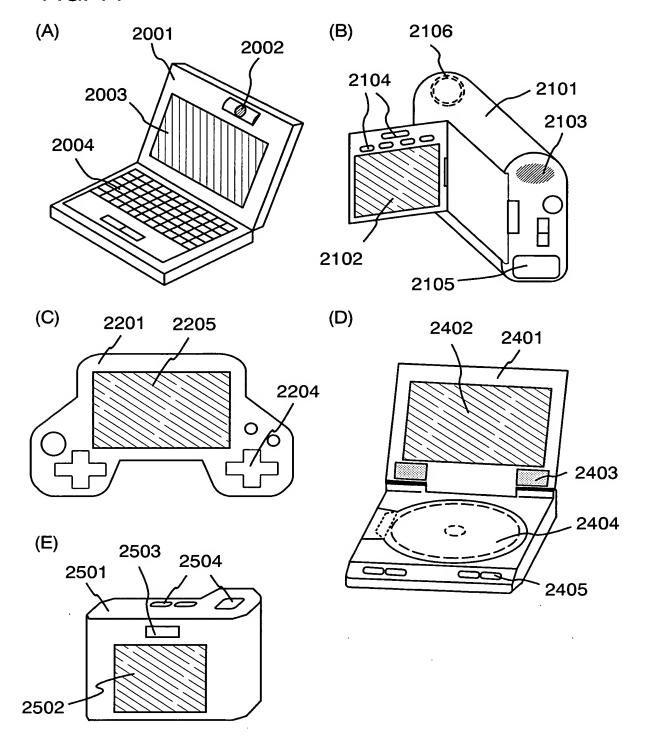
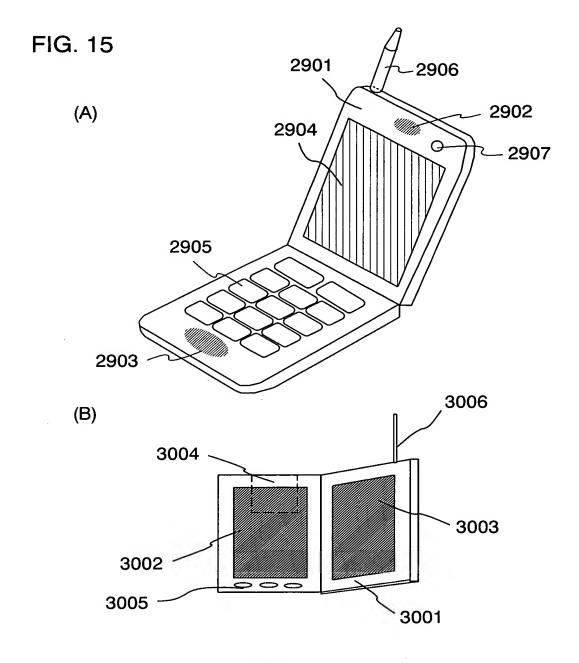


FIG. 14





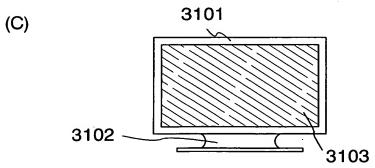
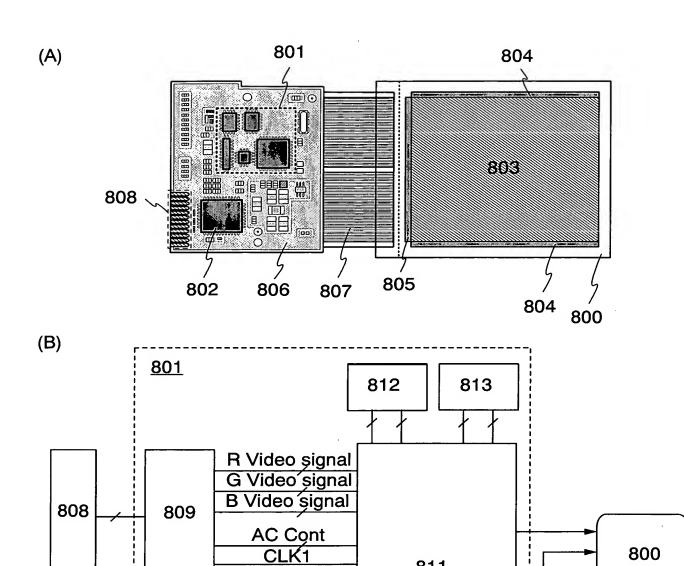


FIG. 16



CLK2

H sync V sync

810

811

802

800

